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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 1 of 1

Complete if Known	
Application Number	10/680,158
Filing Date	October 8, 2003
First Named Inventor	Chandra Mouli
Art Unit	N/A
Examiner Name	Not Yet Assigned
Attorney Docket Number	M4065.0985/P985

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Document Number Number-Kind Code[2] (*if known*)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	AA	2002/0113294 A1	08/22/2002	Rhee et al.	
	AB	2002/0125536 A1	09/12/2002	Iwasa	
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Foreign Patent Document Country Code[3]-Number[4]-Kind Code[5] (*if known*)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T[6]

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. [1] Applicant's unique citation designation number (optional). [2] See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. [3] Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). [4] For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. [5] Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. [6] Applicant is to place a check mark here if English language Translation is attached.

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T[2]
	CA	Alain Chun-Keung Chan et al. – "Effects of Floating Body on Double Polysilicon Partially Depleted SOI Nonvolatile Memory Cell," IEEE Electron Device Letters, 2003, pgs. 1-3.	
	CB	P. Fazan et al. – "Capacitor-Less 1-Transistor DRAM," IEEE International SOI Conference, October 2002, pgs. 10-13.	
	CC	Kazumi Inoh et al. – "FBC (Floating Body Cell) for Embedded DRAM on SOI," 2003 Symposium on VLSI Technology Digest of Technical Papers, June 2003, 2 pages.	
	CD	~~Jean-Michel Sallese et al. – "Principles of the 1-T DRAM Concept on SOI," MIXDES 02, 19 pages.~~	

no date

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